

## NJM062/064

The NJM062/064 are J-FET input operational amplifiers which were designed as low-power versions of the NJM082. They feature high input impedance, wide bandwidth, high slew rate, and low input offset and bias current. The NJM062 features the same terminal assignments as the NJM4558/2043/2904/3404/072 and NJM064 features the same terminal assignments as the NJM2902/3403/2058/2059/2060. Each of these JFET-input operational amplifiers incorporates well-matched, high-voltage JFET and bipolar transistors in a monolithic integrated circuit.

## ■ Absolute Maximum Ratings (Ta=25°C)

Supply Voltage	V <sup>+</sup> /V <sup>-</sup>	±18V
Differential Input Voltage	V <sub>ID</sub>	±30V
Input Voltage (note 1)	V <sub>I</sub>	±15V
Power Dissipation	P <sub>D</sub> (DIP-8) (DMP-8, EMP-8) (SIP-8) (DIP14) (DMP14)(note2)	500mW 300mW 800mW 700mW 700mW
Operating Temperature Range	T <sub>opr</sub>	-20~+75°C
Storage Temperature Range	T <sub>sig</sub>	-40~+125°C

(note 1) For supply voltages less than ±15V, the absolute maximum input voltage is equal to the supply voltage.

(note 2) at on PC board

## ■ Package Outline



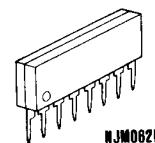
NJM062D



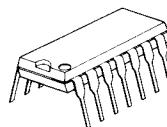
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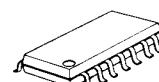
NJM062E



NJM062L



NJM064D



NJM064M

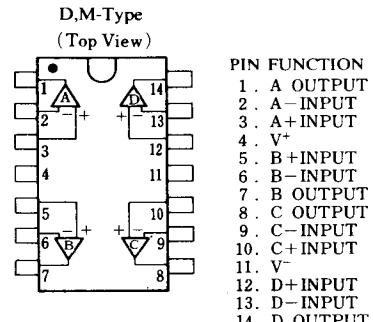
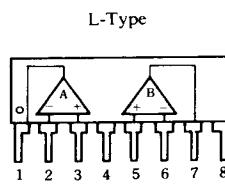
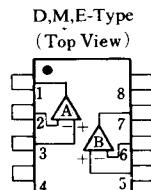
■ Electrical Characteristics (Ta=25°C, V<sup>+</sup>/V<sup>-</sup>=±15V)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Operating Supply Voltage	V <sup>+</sup> /V <sup>-</sup>		±2	—	±18	V
Input Offset Voltage	V <sub>IO</sub>	R <sub>S</sub> =50Ω	—	3	15	mV
Input Offset Current	I <sub>IO</sub>		—	1	200	pA
Input Bias Current	I <sub>B</sub>		—	2	400	pA
Input Common Mode Voltage Range	V <sub>ICM</sub>		±13	+15.0 —3.2 —14.0	—	V
Maximum Peak-to-peak Output Voltage Swing	V <sub>OM</sub>	R <sub>L</sub> =10kΩ	±13	+14.2 —	—	V
Large-signal Voltage Gain	A <sub>V</sub>	R <sub>L</sub> ≥10kΩ, V <sub>O</sub> =±10V	70	80	—	dB
Unity Gain Bandwidth	GB	R <sub>L</sub> =10kΩ	—	1	—	MHz
Input Resistance	R <sub>IN</sub>		—	10 <sup>12</sup>	—	Ω
Common Mode Rejection Ratio	CMR	R <sub>S</sub> ≤10kΩ	70	90	—	dB
Supply Voltage Rejection Ratio	SVR	R <sub>S</sub> ≤10kΩ	70	100	—	dB
Power Dissipation	P <sub>D</sub>	R <sub>L</sub> =∞each amplifier	—	6	7.5	mW
Quiescent Current	I <sub>CC</sub>	R <sub>L</sub> =∞each amplifier	—	200	250	μA
Slew Rate	SR	R <sub>L</sub> =10kΩ	—	3.5	—	V/μs
Equivalent Input Noise Voltage	V <sub>NI</sub>	R <sub>S</sub> =100Ω, f=1kHz	—	35	—	nV/√Hz

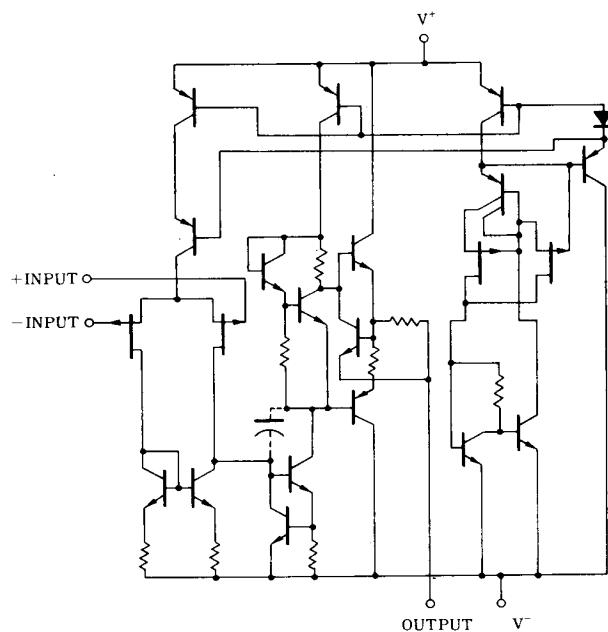
## ■ Electrical Characteristics (Ta=25°C, V<sup>+</sup>/V<sup>-</sup>=±15V)

Parameter	Symbol	Test Condition	064			
			Min.	Typ.	Max.	
Input Offset Voltage	V <sub>IO</sub>	R <sub>S</sub> =50Ω	—	3	15	mV
Input Offset Current	I <sub>IO</sub>	—	—	5	200	pA
Input Bias Current	I <sub>IB</sub>	—	—	30	400	pA
Input Common Mode Voltage Range	V <sub>ICM</sub>	—	±10	±11	—	V
Maximum Peak-to-peak Output Voltage Swing	V <sub>OM</sub>	R <sub>L</sub> =10kΩ	20	27	—	V
Large Signal Voltage Gain	A <sub>V</sub>	R <sub>L</sub> ≥10kΩ, V <sub>O</sub> =±10V	70	76	—	dB
Unity Gain Bandwidth	GB	R <sub>L</sub> =10kΩ	—	1	—	MHz
Input Resistance	R <sub>IN</sub>	—	—	10 <sup>12</sup>	—	Ω
Common Mode Rejection Ratio	CMR	R <sub>S</sub> ≤10kΩ	70	76	—	dB
Supply Voltage Rejection Ratio	SVR	R <sub>S</sub> ≤10kΩ	70	95	—	dB
Power Dissipation	P <sub>D</sub>	R <sub>L</sub> =∞each amplifier	—	6	7.5	mW
Quiescent Current	I <sub>CC</sub>	R <sub>L</sub> =∞each amplifier	—	200	250	μA
Slew Rate	SR	R <sub>L</sub> =10kΩ	—	3.5	—	V/μs
Equivalent Input Noise Voltage	V <sub>NI</sub>	R <sub>S</sub> =100Ω, f=1kHz	—	42	—	nV/√Hz

## ■ Connection Diagram



NJM062



## ■ Equivalent Circuit

(062 is 1/2 Shown, 064 is 1/4 Shown)

## ■ Typical Characteristics

